

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	24665	SOI or (silicon adj on adj insulator)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
2	BRS	L2	1468535	channel	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
3	BRS	L3	7093	buried adj3 (oxide or insulator)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
4	BRS	L4	915965	gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
5	BRS	L5	6030	oxygen near3 (implant\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
6	BRS	L6	4516	1 same 2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
7	BRS	L7	702	3 same 6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
8	BRS	L8	442	4 same 7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
9	BRS	L9	155	5 and 8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
10	BRS	L10	19	5 same 8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
11	BRS	L11	136	9 not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
12	BRS	L12	4144	257/347	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
13	BRS	L14	318	257/524	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
14	BRS	L13	856	257/349	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp
1	2005/02/05 11:48
2	2005/02/05 11:48
3	2005/02/05 11:49
4	2005/02/05 11:49
5	2005/02/05 11:51
6	2005/02/05 11:51
7	2005/02/05 11:51
8	2005/02/05 11:51
9	2005/02/05 12:05
10	2005/02/05 11:51
11	2005/02/05 12:39
12	2005/02/05 12:39
13	2005/02/05 12:42
14	2005/02/05 12:46